Electronic supporting Information

Effects of Aromatic Spacers on the Properties of Organic Field Effect Transistors based on π -Extended Tetrathiafulvalene Derivatives

Olivier Alévêque,^a Pierre Frère,^{*a} Philippe Leriche,^a Tony Breton,^a Antonio Cravino^a and Jean Roncali^a

Figure S1 : X-ray diffraction of films of compound 1-5 deposited on glass	2-4
Figure S2 : Structure of the calculated δ -trans conformations of compounds 1-5	6
Figure S3 : Characteristics of OFETs built with compounds 1-5 in a glove box	7 - 8



Fig. S1a : X-ray diffraction of film of compound 1 deposited on glass



Fig. S1b : X-ray diffraction of film of compound 2 deposited on glass



Fig. S1c : X-ray diffraction of film of compound 3 deposited on glass



Fig. S1d : X-ray diffraction of film of compound 4 deposited on glass



Fig. S1e : X-ray diffraction of film of compound **5** deposited on glass



Fig S2 : Structure of the calculated conformations (density functional theory at the B3LYP/6- 31G(d) level) of compounds 1-5



Figure S3a : Characteristics of OFET built with compounds **1** in a glove box.



Figure S3b : Characteristics of OFET built with compounds **2** in a glove box.



Figure S3c : Characteristics of OFET built with compounds **3** in a glove box.



Figure S3d : Characteristics of OFET built with compounds **4** in a glove box.



Figure S3e : Characteristics of OFET built with compounds **5** in a glove box.